NSN 5961-01-247-9483

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Inclosure Material:

Ceramic and metal

Overall Length:

28.2 millimeters

Overall Height:

17.6 millimeters

Overall Width:

28.2 millimeters

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

4.0 emitter to base voltage, dc

Current Rating Per Characteristic:

0.32 amperes source cutoff current

Power Rating Per Characteristic:

9.6 watts small-signal input power, common-collector preset

Transfer Ratio:

10.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unc

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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